20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A. TELEPHONE: (201) 376-2922

(212) 227-6005

FAX: (201) 376-8960

PRODUCT SPECIFICATIONS

HIGH CONDUCTANCE, GENERAL PURPOSE

SILICON PLANODE**

1N461A 1N463A 1N462A 1N464A

The 1N461A PLANODE** family, with one-piece whiskerless planar construction, offers the ultimate in electrical and mechanical reliability. Die and studs are metallurgically bonded into one massive structure. Thermal and mechanical shock are distributed throughout this structure instead of concentrating at a delicate whisker contact. PLANODE** construction, plus Raytheon's MARK X and optional X-L Reliability Processing, insures ultimate reliability.

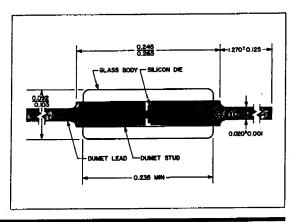
MECHANICAL DATA

CASE:

JEDEC DO-7

MARKING:

Standard E.I.A. color code bands starting at cathode end.



ELECTRICAL DATA

BSOLUTE MAXIMUM RATINGS:														
Average Rectified Current, Io, 25°C	,		,											200 m
Average Rectified Current, Io, 150°C								,		,		,		70 m
Surge Current (1 sec), if (surge), 25°C.														1500 m
Surge Current (1 sec), if (surge) 150°C						,								1000 m
Power Dissipation @ 25° C														500 m\
Operating Temperature												-6	5°C	to +200°
Storage Temperature					٠.			,				-6	5°C	to +200°

LECTRICAL CHARACTERISTIC	CS: @25°	C (unless oth				
	Working Inverse	Minimum Forward		aximum Invo rent at Spec	Minimum Saturation	
Туре	Voltage	Current	,	(Aب) Voltage)	Voltage
**	(Volts)	@. 1.0 Volt (mA)	25° C	150° C	Volts	@ 100 µA (Volts)
1N461A	25	100	0.5	30	25	30
1N462A	60	100	0.5	30	60	70
1N463A	175	100	0.5	30	175	200
1 N464A	125	100	0.5	30	125	150

